















ESD

TVS

MOS

LDO

Diode

Sensor

DC-DC

Product Specification

Domestic Part Number	UC3842/43/44/45
Overseas Part Number	UC3842/43/44/45
▶ Equivalent Part Number	UC3842/43/44/45





Description

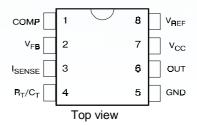
The 3842/43/44/45 are fixed frequency current mode PWM controller. They are specially designed for OFF-Line and DC to DC converter applications with a minimal external components. Internally implemented circuits include a trimmed oscillator for precise duty cycle control, a temperature compensated reference, high gain error amplifier, current sensing comparator, and a high current totempole output ideally suited for driving a power MOSFET. Protection circuitry includes built undervoltage lockout and current limiting. The 3842 and 3844 have UVLO thresholds of 16 V (on) and 10 V (off). The corresponding thresholds for the 3843/ 45 are 8.4V (on) and 7.6V (off). The 3842) and 3843 can operate within 100% duty cycle. The 3844 and 3845 can operate within 50% duty

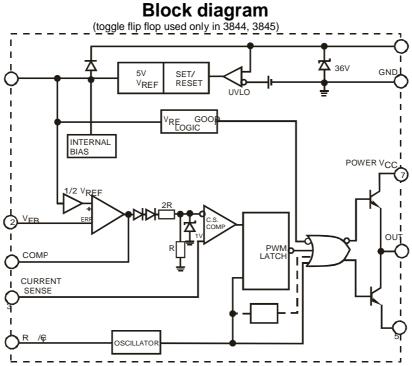
The 384X has Start-Up Current 0.17mA (typ).

Features

- Low Start-Up and Operating Current
- High Current Totem Pole Output
- Undervoltage Lockout With Hysteresis
- Operating Frequency Up To 300KHz (384X) 500KHz (384X)

Pin Connection





Absolute Maximum Ratings

Symbol	Parameter	Maximum	Units
V _{CC}	Supply Voltage (low impedance source)	30	V
Io	Output Current	±1	Α
Vı	Input Voltage (Analog Inputs pins 2,3)	-0.3 to 5.5	V
I _{SINK (E.A)}	Error Amp Output Sink Current	10	mA
Po	Power Dissipation (T _A =25 ^o C)	1	W
Tstg	Storage Temperature Range	-65 to150	°C
T _L	Lead Temperature (soldering 5 sec.)	260	°C.



Electrical characteristics

 $(^*V_{CC}=15V, R_T=10k\Omega, C_T=3.3nF, T_A=0^{0}C$ to $+70^{0}C$, unless otherwise specified)

Characteristics	Symbol	Test Conditions		Min	Тур	Max	Units	
Reference Section								
Reference Output Voltage	Vref	$T_J = 25$ °C, $I_{REF} =$	1 mA	4.9	5.0	5.1	V	
Line Regulation	ΔV_{REF}	12V ≤ Vcc ≤ 25 V			6.0	20	mV	
Load Regulation	ΔV_{REF}	1 mA ≤ Iref ≤ 20mA			6.0	25		
Short Circuit Output Current	Isc	T _A = 25°C			-100	-180	mA	
Oscillator Section	•							
Oscillation Frequency	f	T _J = 25°C	384X	47	50	57	KHz	
			384X	47	52	57		
Frequency Change with Voltage	Δf/ΔV _{CC}	12V ≤ Vcc ≤	25 V		0.05	1.0	%	
Oscillator Amplitude	V _(OSC)	(peak to peak)			1.6		V	
Error Amplifier Section					•			
Input Bias Current	I _{BIAS}	V _{FB} =3V			-0.1	-2	μA	
Input Voltage	V _{I(E.A)}	$V_{pin1} = 2.5V$		2.42	2.5	2.58	V	
Open Loop Voltage Gain	A _{VOL}	$2V \leqslant V_0 \leqslant 4V$,	65	90		٩D	
Power Supply Rejection Ratio	PSRR	$12V \leqslant V_{CC} \leqslant$	25 V	60	70		dB	
Output Sink Current	I _{SINK}	$V_{pin2} = 2.7V, V_{pin1}$	= 1.1V	2	7		mA	
Output Source Current	I _{SOURCE}	$V_{pin2} = 2.3V, V_{pin1}$	= 5V	-0.5	-1.0		mA	
High Output Voltage	Vон	$V_{\text{pin2}} = 2.3V$, $R_{\text{L}} = 15$ KΩ to GND		5.0	6.0		W	
Low Output Voltage	Vol	$V_{pin2} = 2.7V$, $R_L = 15K\Omega$ to PIN 8			0.8	1.1	V	
Current Sense Section	•			•	•	•	•	
Gain	G _V	(Note 1 & 2)		2.85	3.0	3.15	V/V	
Maximum Input Signal	V _{I(MAX)}	V _{pin1} = 5V (Note1)		0.9	1.0	1.1	V	
Supply Voltage Rejection	SVR	12V ≤ V _{CC} ≤ 25 V (Note 1)			70		dB	
Input Bias Current	I _{BIAS}	$V_{pin3} = 3V$			-3.0	-10	μA	
Output Section								
Low Output Voltage	V _{OL}	I _{SINK} = 20 mA			0.08	0.4	V	
		I _{SINK} = 200 mA			1.4	2.2		
High Output Voltage	V _{OH}	I _{SINK} = 20 mA		13	13.5			
		I _{SINK} = 200 mA		12	13.0			
Rise Time	ṫ̀R	$T_J = 25^{\circ}C, C_L = 1nF \text{ (Note 3)}$			45	150	nS	
Fall Time	t⊧	$T_J = 25^{\circ}C, C_L = 1nF \text{ (Note 3)}$			35	150	113	
Undervoltage Lockout Section								
Start Theshold	V _{TH(ST)}		3842/44	14.5	16.0	17.5	_ v	
			3843/45	7.8	8.4	9.0		
Min. Operating Voltage	V _{OPR(min)}	:	3842/44	8.5	10	11.5	V	
(After Turn On)		3843/45 7.0		7.6	8.2			
PWM Section	-							
Max. Duty Cycle	D _(MAX)		3842/43	95	97	100	%	
			3844/45	47	48	50		
Min. Duty Cycle	D _(MAX)					0		
Total Standby Current	1						ı	
Start-Up Current	I _{ST}	384X			0.17	0.3	mA	
Operating Supply Current	I _{CC (OPR)}	$V_{pin3} = V_{pin2} = 0V$			13	17		
Zener Voltage	Vz	I _{CC} =25 mA		30	38		V	

^{* -} Adjust V_{CC} above the start threshold before setting it to 15V.

Note 1: Parameter measured at ting point of latch with V_{pin2} =0. Note 2: Gain defined as $A=\Delta V_{pin1}/\Delta V_{pin3}$; $0 \le V_{pin3} \le 0.8V$. Note 3: These parameters, although guaranteed, are not 100% tested in production.



Pin functions

N	Function	Description			
1	COMP	This pin is the Error Amplifier output and is made for loop compensation.			
2	V _{FB}	This is the inverting input of the Error Amplifier. It is normally connected to the switching power supply output through a resistor divider.			
3	I _{SENSE}	A voltage proportional to inductor current is connected to this input. The PWM uses this information to terminate the output switch conduction.			
4	R _T /C _T	The oscillator frequency and maximum Output duty cycle are programmed by connecting resistor R_T to V_{ref} and capacitor C_T to ground.			
5	GROUND	This pin is the combined control circuitry and power ground.			
6	OUTPUT	This output directly drives the gate of a power MOSFET. Peak currents up to 1A are sourced and sink by this pin.			
7	Vcc	This pin is the positive supply of the integrated circuit.			
8	V_{ref}	This is the reference output. It provides charging current for capacitor C_T through resistor R_T .			

Application information

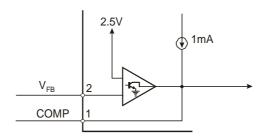


Figure 1. Error Amp Configuration

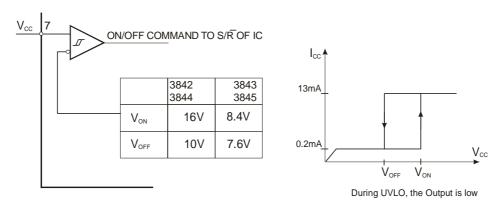


Figure 2. Undervoltage Lockout

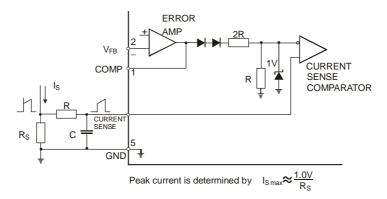


Figure 3. Current Sense Circuit



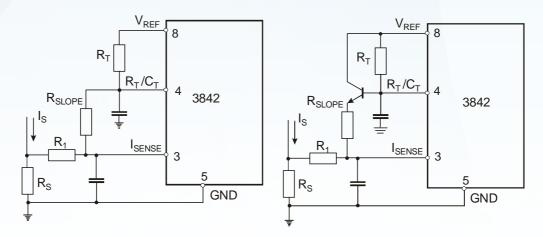
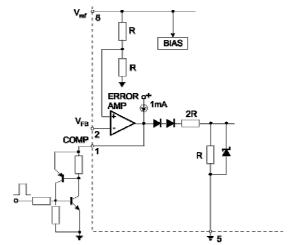


Figure 4. Slope Compensation Techniques



SCR must be selected for a holding current of less than 0.5mA. The simple two transistor circuit can be used in place of the SCR as shown.

Figure 5. Latched Shutdown

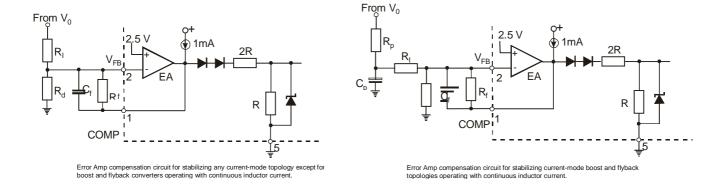


Figure 6. Error Amplifier Compensation



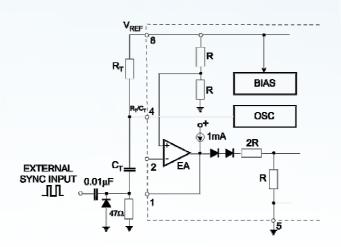


Figure 7. External Clock Synchronization

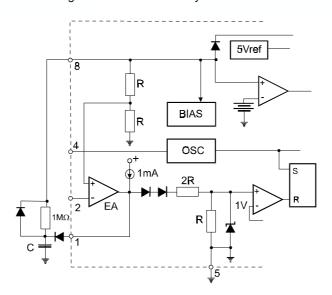
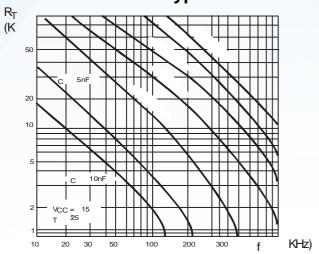


Figure 8. Soft-Start Circuit



Typical Performance Characteristics



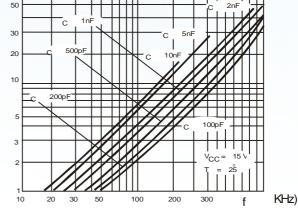
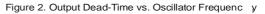
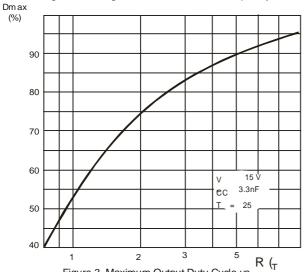
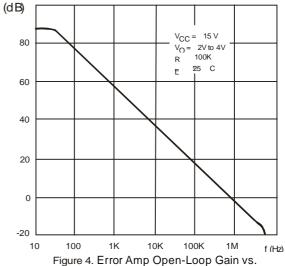
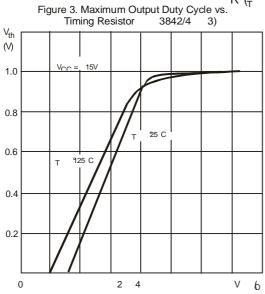


Figure 1. Timing Resistor vs. Oscillator Frequency.









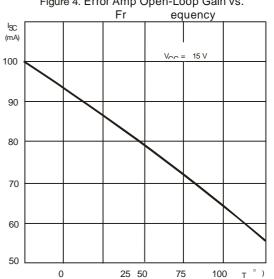
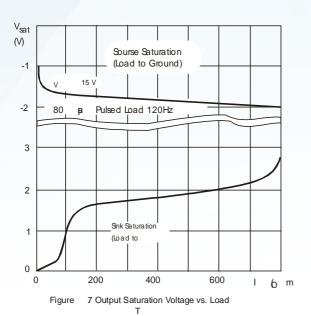
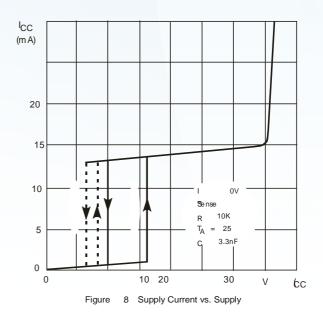


Figure 5. Current Sense Input Threshold vs. Error Amp Output Voltage.

Figure 6. Reference Short Circuit Current vs. Temperature.







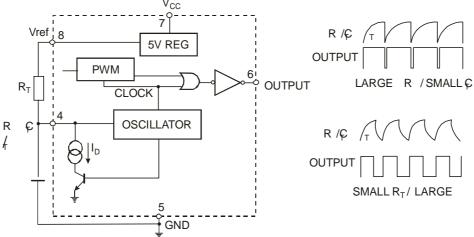


Figure 9. Oscillator and Output Waveforms



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